

Features

- ESD Protected Up To 2KV(HBM)
- Very Low FOM $R_{DS(on)} \times Q_g$
- Moisture Sensitivity Level 3
- Halogen Free. "Green" Device (Note1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

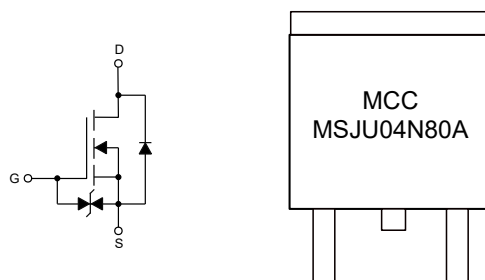
- Operating Junction Temperature Range : -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance:50°C/W Junction to Ambient^(Note2)
- Thermal Resistance:1.41°C/W Junction to Case

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V_{DS}	800	V
Gate-Source Voltage	V_{GS}	±20	V
Continuous Drain Current	I_D	$T_C=25^\circ\text{C}$	4.5
		$T_C=100^\circ\text{C}$	2.8
Pulsed Drain Current ^(Note3)	I_{DM}	18	A
Total Power Dissipation ^(Note4)	P_D	88	W
Single Pulsed Avalanche Energy ^(Note5)	E_{AS}	50	mJ

Note:

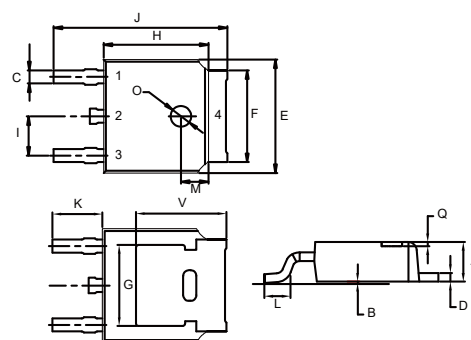
1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. The value of $R_{\theta JA}$ is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with $T_A=25^\circ\text{C}$.
3. Repetitive rating; pulse width limited by max. junction temperature.
4. P_D is based on max. junction temperature, using junction-case thermal resistance.
5. $T_J=25^\circ\text{C}$, $V_{DD}=50\text{V}$, $R_G=25\Omega$, $V_{GS}=10\text{V}$, $L=50\text{mH}$.

Internal Structure and Marking Code



N-CHANNEL Super-Junction Power MOSFET

DPAK(TO-252)



1. Gate
- 2,4. Drain
3. Source

DIM	DIMENSIONS				NOTE
	INCHES		MM		
	MIN	MAX	MIN	MAX	
A	0.087	0.094	2.20	2.40	
B	0.000	0.005	0.00	0.13	
C	0.026	0.034	0.66	0.86	
D	0.018	0.023	0.46	0.58	
E	0.256	0.264	6.50	6.70	
F	0.201	0.215	5.10	5.46	
G	0.190		4.83		TYP.
H	0.236	0.244	6.00	6.20	
I	0.086	0.094	2.18	2.39	
J	0.386	0.409	9.80	10.40	
K	0.114		2.90		TYP.
L	0.055	0.067	1.40	1.70	
M	0.063		1.60		TYP.
O	0.043	0.051	1.10	1.30	
Q	0.000	0.012	0.00	0.30	
V	0.211		5.35		TYP.

Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=250\mu A$	800			V
Gate-Source Leakage Current	I_{GSS}	$V_{DS}=0V, V_{GS}=\pm 20V$			± 10	μA
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS}=800V, V_{GS}=0V$			1	μA
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=250\mu A$	2.5	3.6	4.5	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS}=10V, I_D=2.5A$		0.97	1.3	Ω
Gate Resistance	R_G	f=1MHz, Open drain		21		Ω
Diode Characteristics						
Continuous Body Diode Current	I_S				4.5	A
Diode Forward Voltage	V_{SD}	$V_{GS}=0V, I_S=4.5A$			1.4	V
Reverse Recovery Time	t_{rr}	$I_S=4.5A, di/dt=100A/\mu s$		260		ns
Reverse Recovery Charge	Q_{rr}			2020		nC
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS}=100V, V_{GS}=0V, f=400KHz$		386		pF
Output Capacitance	C_{oss}			13		
Reverse Transfer Capacitance	C_{rss}			0.9		
Total Gate Charge	Q_g	$V_{DS}=640V, V_{GS}=10V, I_D=4.5A$		11.7		nC
Gate-Source Charge	Q_{gs}			2		
Gate-Drain Charge	Q_{gd}			6		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD}=400V, V_{GS}=10V, R_G=25\Omega, I_D=4.5A$		11		ns
Turn-On Rise Time	t_r			27		
Turn-Off Delay Time	$t_{d(off)}$			54		
Turn-Off Fall Time	t_f			22		

Curve Characteristics

Fig. 1 - Typical Output Characteristics

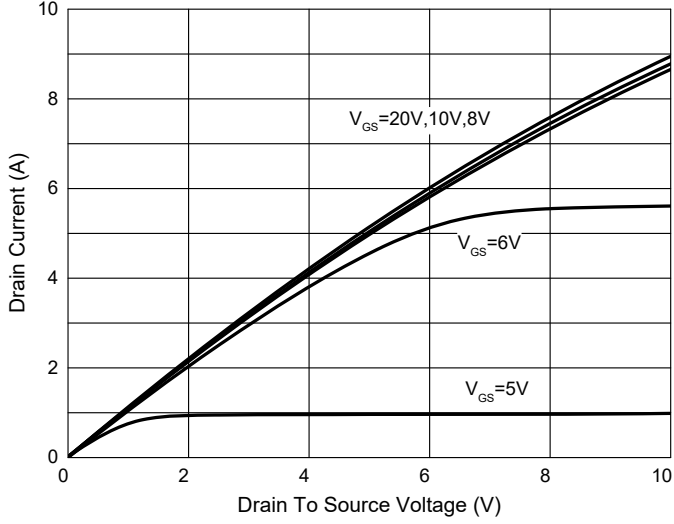


Fig. 2 - Transfer Characteristics

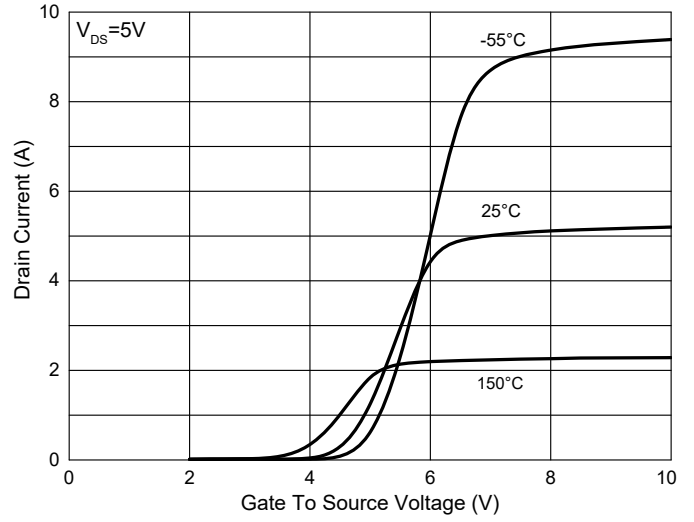


Fig. 3 - $R_{DS(ON)} - V_{GS}$

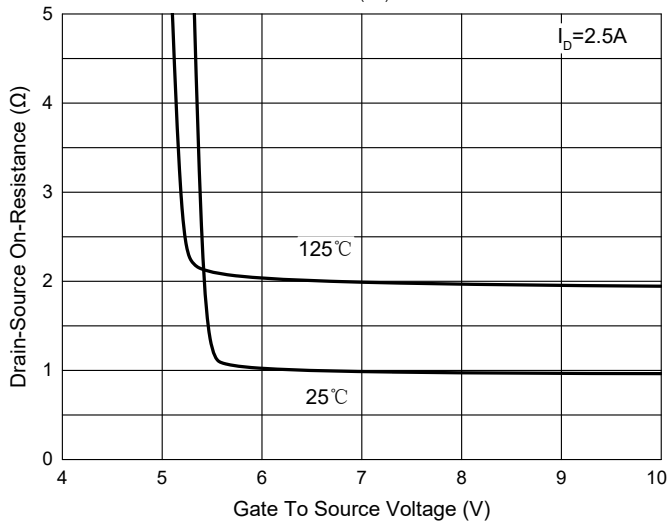


Fig. 4 - $R_{DS(ON)} - I_D$

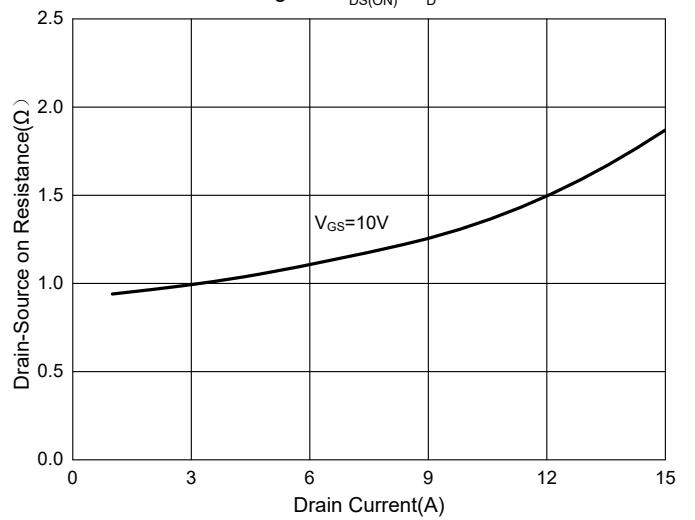


Fig. 5 - Capacitance Characteristics

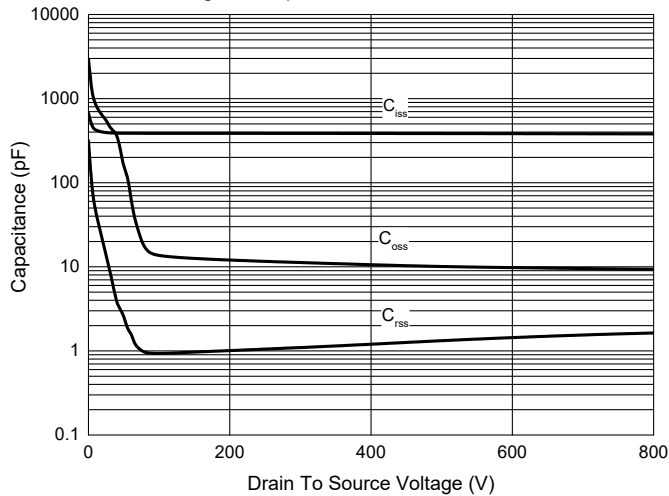
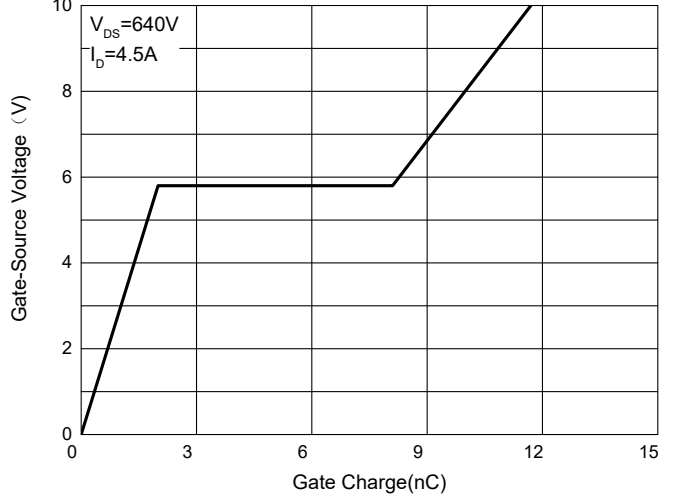


Fig. 6 - Gate Charge



Curve Characteristics

Fig. 7 - Normalized Threshold Voltage

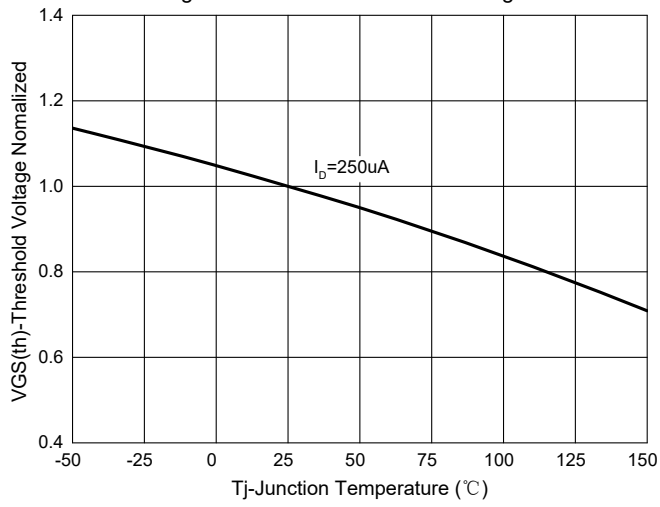


Fig.8-Normalized On Resistance Characteristics

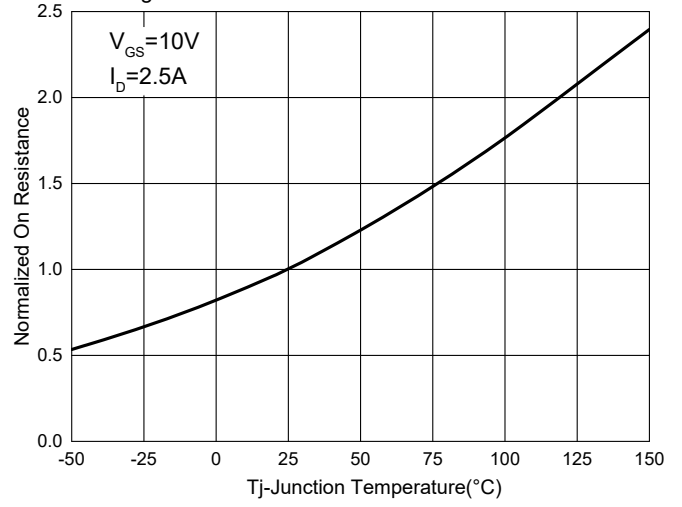


Fig.9 - $I_S - V_{SD}$

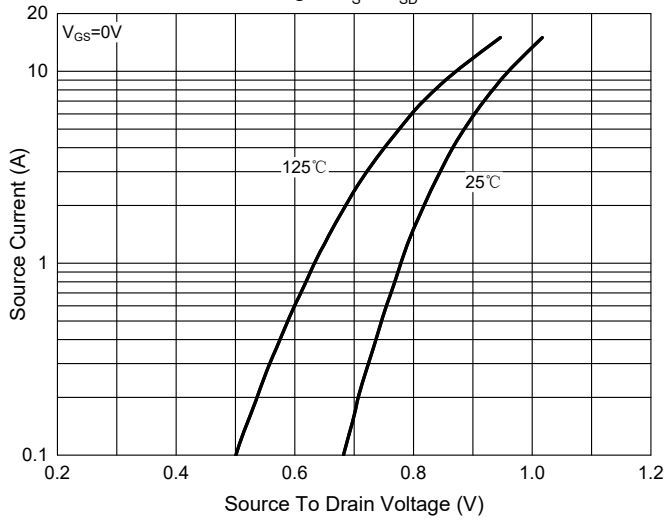


Fig. 10 - Drain Current

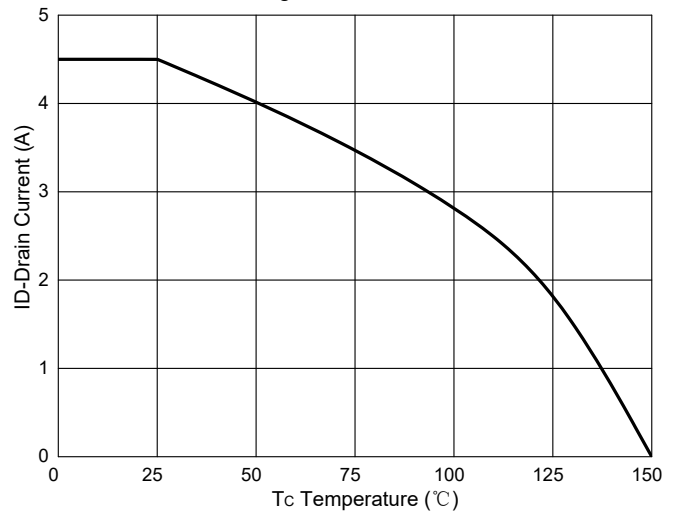
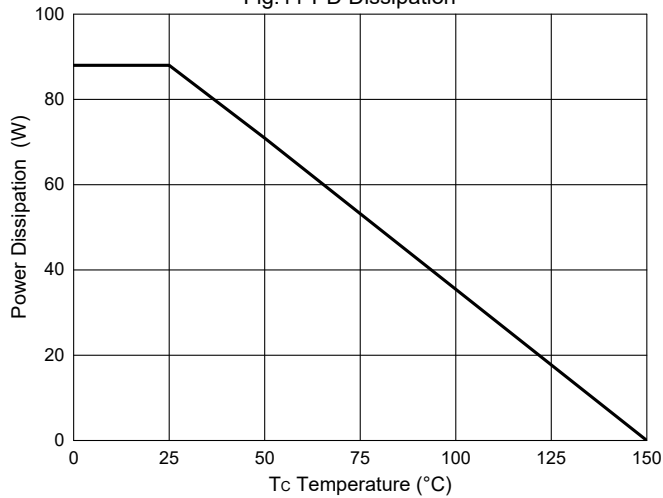


Fig.11-PD Dissipation



Curve Characteristics

Fig. 12 - Safe Operation Area

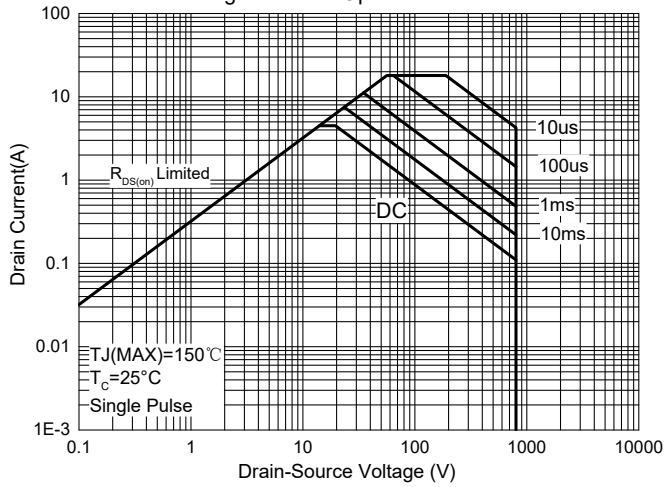
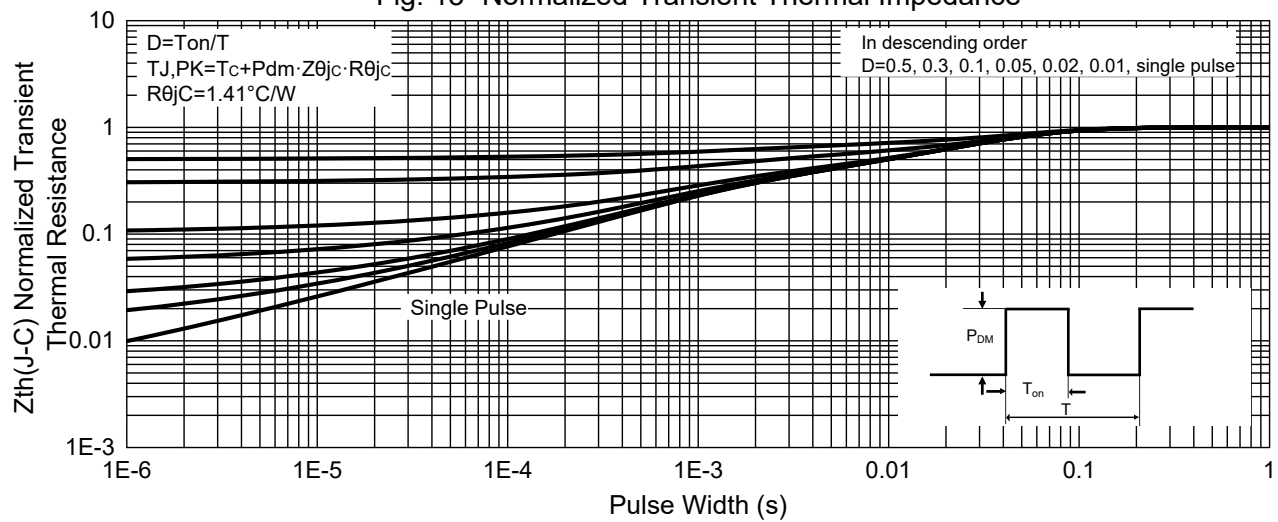


Fig. 13 - Normalized Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel: 2.5Kpcs/Reel

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